OPB750N, OPB750T OPB755TZ, OPB755TAZ Obsolete (OPB755NZ)

#### Features:

- High contrast ratio (1,000:1 minimum)
- · Low cost plastic housing
- PCBoard mount (OPB750N, OPB750T)
- 12" (305 mm) 26 AWG wires (OPB755TZ)
- Available with no-mounting tabs "N" package
- Available with two mounting tabs "T" package



#### **Description:**

Each sensor in the **OPB750** and **OPB755** series has a reflective assembly that features a Light Emitting Diode (LED) and phototransistor output designed to decrease low-level light, while not affecting the high-level light gain.

The **OPB750N** and **OPB750T** devices are designed for PCBoard mounting with 0.40" (10 mm) length leads. **OPB755TZ** and **OPB755TAZ** assemblies are designed for remote mounting. The **OPB755TZ** has 12" (305 mm) UL rated wire, 26 AWG wire leads that terminate into an AMP # 3-640442-5 connector. The **OPB755TAZ** has 24" (610 mm) UL rated wire, 26 AWG leads. The **OPB750T, OPB755TZ** and **OPB755TAZ** have two mounting tabs while the **OPB750N** has no mounting tabs.

Photologic® output versions are available with the **OPB760** and **OPB770** series.

Custom electrical, wire and cabling and connectors are available. Contact your local representative or OPTEK for more information.

#### **Applications:**

- Non-contact reflective object sensor
- Assembly line automation
- Machine automation
- Machine safety
- End of travel sensor
- Door sensor

Ordering Information									
Part LED Peak		Sensor	<b>Reflection Distance</b>	Distance Lead					
Number	er Wavelength		Inch	Length	Tabs				
			0.080" (2.03 mm)						
OPB750N			0.150" (3.81 mm)		No tabs				
	000	Transis-	0.220" (5.59 mm)	0.40"					
	890 nm	tor & Rbe	0.080" (2.03 mm)	0.40"	2 tabs				
OPB750T		& NDE	0.150" (3.81 mm)						
			0.220" (5.59 mm)						
00075517			0.080" (2.03 mm)		No tabs				
OPB755NZ Obsolete	TZ 890 nm	Transis- tor	0.150" (3.81 mm)	12" / 26					
Obsolete			0.220" (5.59 mm)	AWG					
			0.080" (2.03 mm)	Wire with	2 tabs				
OPB755TZ			0.150" (3.81 mm)	connector					
			0.220" (5.59 mm)						
OPB755TAZ		& Rbe	0.080" (2.03 mm)	24" / 26					
			0.150" (3.81 mm)	AWG					
				0.220" (5.59 mm)	Wire NO				
			- ()	connector					

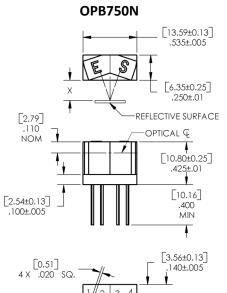


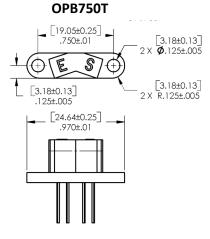
General Note

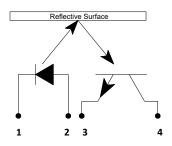
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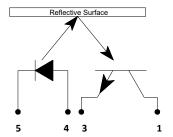




OPB750								
Pin # Description								
1	Cathode							
2	Anode							
4	Collector							
3	Emitter							

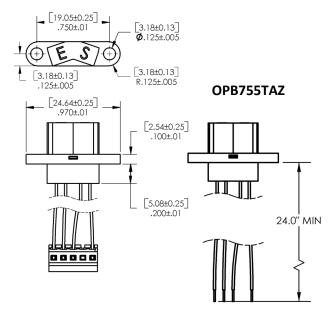
0.51] 4 X .020 SQ.	 [3.56±0.13] .140±.005
[4.58] 4.32] .180 .170	4.45 4.19 .175 .03±0.13 .165 080±.005

DIMENSIONS ARE IN: [MILLIMETERS] INCHES



OPB755					
Color	Description				
Black-5	Cathode				
Red-4	Anode				
White-1	Collector				
Green-3	Emitter				

#### OPB755TZ



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Obsolete (OPB755NZ)



#### **Absolute Maximum Ratings** (T<sub>A</sub> = 25° C unless otherwise noted)

Operating and Storage Temperature Range	
OPB750N, OPB750T	-40° C to + 85° C
OPB755TZ, OPB755TAZ	-40° C to + 80° C
Lead Soldering Temperature <sup>(1)</sup>	260° C

### **Input Diode**

Forward DC Current	50 mA
Peak Forward Current (1 μ pulse width, 300 pps)	1 A
Reverse DC Voltage	2 V
Power Dissipation	100 mW

#### **Output Phototransistor**

Collector-Emitter Voltage	24 V
Collector DC Current	30 V
Power Dissipation <sup>(3)</sup>	100 mW

#### Electrical Characteristics (T<sub>A</sub> = 25° C unless otherwise noted)

SYMBOL	PARAMETER	MIN	TYP	MAX	UNITS	TEST CONDITIONS
Input Diode (See OP240 for additional information)						

$V_{F}$	Forward Voltage	1	-	1.8	V	I <sub>F</sub> = 40 mA
$I_R$	Reverse Current	ı	-	100	μΑ	V <sub>R</sub> = 2 V

#### Output Phototransistor (see OP550 for additional information)

V <sub>(BR)CEO</sub>	Collector-Emitter Breakdown Voltage	24	-	-	V	Ι <sub>C</sub> = 100 μΑ
I <sub>CEO</sub>	Collector Dark Current	-	-	100	nA	V <sub>CE</sub> = 10 V, I <sub>F</sub> = 0, H = 0

#### Coupled

١	V <sub>CE(SAT)</sub>	Saturation Voltage	-	-	.40	V	I <sub>C</sub> = 150 μA, I <sub>F</sub> = 30 mA, d = 0.22"
	I <sub>C(OFF)</sub>	Off-State Collector Current <sup>(5)</sup>	-	-	250	nA	I <sub>F</sub> = 30 mA, V <sub>CE</sub> = 5 V d = 0.08", 0.15", 0.22"
	I <sub>C(ON)</sub>	On-State Collector Current <sup>(4)</sup>	500 375 250		1 1 1	μΑ	I <sub>F</sub> = 30 mA, V <sub>CE</sub> = 5 V, d = 0.08" I <sub>F</sub> = 30 mA, V <sub>CE</sub> = 5 V, d = 0.15" I <sub>F</sub> = 30 mA, V <sub>CE</sub> = 5 V, d = 0.22"

#### Notes:

- RMA flux is recommended. Duration can be extended to 10 seconds maximum when flow soldering.
- Derate linearly 1.67 mW/° C above 25° C.
- Methanol or isopropanol are recommended as cleaning agents. Plastic housing is soluble in chlorinated hydrocarbons and ketones.
- Photocurrent is measured using an Eastman Kodak neutral white test card having 90% diffuse reflectance as a reflecting surface. Reference: Eastman Kodak,
- $IC_{(OFF)}$  is the photocurrent measured with current to the input diode and a 5% reflecting surface. All parameters tested using pulse techniques.

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## **Performance**

